

Cite this: *J. Mater. Chem. A*, 2023, **11**, 1817

Catalytic active centers beyond transition metals: atomically dispersed alkaline-earth metals for the electroreduction of nitrate to ammonia†

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Alkaline-earth (AE) metals have rarely been reported to be the active centers in heterogeneous catalysis. However, in nature, Mg cofactors in enzymes exhibit super activity for biochemical reactions. Herein, taking the AE metal single-atom catalyst (AE-SAC) supported on graphene as a representative, we theoretically explore the feasibility of AE metals as active centers in heterogeneous catalysis for the electrocatalytic nitrate (NO_3^-) reduction reaction (e NO_3RR) to produce NH_3 . Intriguingly, the AE metal active centers could strongly adsorb and effectively activate NO_3^- , and catalyze e NO_3RR efficiently, similar to that of the transition-metal active centers. In particular, Ba and Sr SACs coordinated with three nitrogen and one carbon atoms exhibited super e NO_3RR activity with an ultralow limiting potential of -0.05 V, which also showed desirable selectivity and good stability. Mechanistic investigations indicated that, although AE metal elements are highly ionic, they function as transmitters to assist the charge transfer between the catalyst support and NO_3^- as well as effective intermediates, which enables the effective activation of NO_3^- , via the "donation-back donation" mechanism, and further completes the catalytic cycle. Our work could broaden the ideas and lay a theoretical foundation for the development of heterogeneous catalysts with AE metals as active centers.

Received 14th October 2022
Accepted 19th December 2022

DOI: 10.1039/d2ta08027c

rsc.li/materials-a

1. Introduction

Heterogeneous catalysis, mainly based on metal and metal-oxides, plays an important role in modern industries and

emerging renewable energy conversion and storage technology.^{1–3} Active centers of the vast majority of heterogeneous catalysts consist of d-block transition metals (TMs). The underlying physical mechanism can be traced back to the partially filled d orbitals, which enables the electron "donation-back donation" process for the molecule adsorption and activation, as described in the Blyholder model⁴ and the d-band center theory.⁵ Conversely, s-block metals, alkali, and alkaline-earth (AE) metals are generally thought to be chemically inert due to the lack of combined empty and occupied orbitals.⁶ It is known that they are generally prone to lose s valence electrons and form the cations in the compounds, which are hard to change the oxidation state rapidly and reversibly involved in elementary steps of a catalytic cycle. Thus, s-block metals are often considered to be catalytic inactive.⁷

Nevertheless, nature has given us some inspiration.^{8–12} To be specific, magnesium (Mg), as a cofactor in enzymes, has been revealed to play key roles in the photosynthesis system and nucleic acid biochemistry.^{9,10} Mg^{2+} in a cofactor has a proper binding affinity for the oxygenated species, and thus, the cofactor can serve as a Lewis acid for the transfer of a phosphate intermediate from one compound to another or the activation of Mg-bound water molecules to a hydroxide ion.⁸ For example, due to the particularly right affinity of the O atom, Mg^{2+} -bound DNA and RNA polymerases can participate in the neutralization of the polyanionic charge of the nucleic acid, so they work

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† Electronic supplementary information (ESI) available: TDOS of AE-SACs; possible adsorption configurations of *NO_3 on AE-SACs; most stable configurations and corresponding adsorption-free energies of *NO_3 and *H on AE-SACs; free energy diagrams and corresponding intermediate configurations on other AE-SAC systems; adsorption free energies of *NO_3 and *H versus electrode potential on DV-Ba N_3C and DV-Sr N_3C ; free energy diagrams and corresponding intermediate configurations on DV-Ba N_3C and DV-Sr N_3C with consideration of the solvation effect; schematic diagram of three moieties; the key parameters of the AE-SAC systems; the key parameters of *NO_3 and *H adsorption on the AE-SAC systems; the PDS and corresponding U_L on the AE-SAC systems; the ΔE_{ZPE} and $T\Delta S$ for intermediates and free molecules. See DOI: <https://doi.org/10.1039/d2ta08027c>

efficiently.^{9,10} Despite their unique and critical biochemical activities and even the widely used molecular catalysis,¹³ AE metals acting as active centers of the heterogeneous catalyst have been reported rarely.^{14–17} For instance, in 2020, Chen *et al.* first showed that the Mg atom coordinated with N and C atoms embedded in graphene exhibits an excellent four-electron oxygen reduction reaction activity.¹⁴ We found that Mg^{2+} in two-dimensionally layered $\text{Mg}_3(\text{hexaiminotriphenylene})_2$ electrocatalyst serves as the active center to selectively produce H_2O_2 by electroreduction of O_2 .¹⁶

It is known that ammonia (NH_3) is one of the most important chemicals in modern life, which has also been regarded as a potential clean energy carrier.¹⁸ In recent years, the electrocatalytic nitrogen reduction reaction (NRR) to synthesize NH_3 under ambient conditions, driven by renewable energy, has gained considerable attention as an alternative to the traditional Haber–Bosch procedure.^{19–23} However, the low solubility and chemical inertness of N_2 molecules lead to an unsatisfactory NH_3 production rate and Faraday efficiency.^{24–26} In this case, very recently nitrate (NO_3^-), having a much weaker intramolecular chemical bond (176 kJ mol^{-1}) than N_2 (941 kJ mol^{-1}), is emerging as a novel nitrogen resource for NH_3 synthesis.²⁷ Considering the ever-increasing concentration of NO_3^- can severely destroy ecological balance and threaten human health,¹⁹ electrocatalytic nitrate reduction reaction (e NO_3RR) could be considered as a “one stone two bird” strategy for simultaneous nitrate pollution treatment and NH_3 production.^{28,29} Therefore, it is full of importance and challenge to design efficient electrocatalysts with high stability for direct electroreduction of NO_3^- into NH_3 .^{30–32}

Encouragingly, diverse catalysts, such as molecular solids,³³ metallic alloys,²⁹ metallic compounds,^{34,35} pure metals,^{36,37} and atomic catalysts^{38,39} have been proven to be efficient for e NO_3RR , and all the reported catalysts have the TM atoms as active centers. On the other hand, single-atom catalysts (SACs) have gained significant attention in electrocatalysis due to their high efficiency and simple active sites, which makes SAC an ideal platform for studying catalysis mechanisms through theoretical calculations.^{40–42} For e NO_3RR , several SACs have been reported experimentally^{32,38,43,44} or theoretically.^{45–52} Interestingly, for these SACs, it is predicted that the binding strength of NO_3^- could serve as a descriptor to predict the activity trend, and the active center with the adsorption-free energy for NO_3^- ($\Delta G^*(\text{NO}_3^-)$) of around -2.0 eV exhibiting a high e NO_3RR activity. Considering that AE ions have a unique affinity for the oxygenated species,^{14,16} the catalysts with AE ions as active sites may be able to bind NO_3^- effectively; moreover, by tuning the coordination environment or the metal center identities (Mg, Ca, Sr, and Ba), a suitable binding strength of NO_3^- and nice e NO_3RR activity could be achieved.^{53,54} However, the direct electroreduction of NO_3^- into NH_3 by the AE metal active centers in the electrocatalysts has not been explored and remains an open challenge.

In this work, taking AE metal single atom incorporated graphene as representatives, we comprehensively explored the feasibility of AE metals as active centers for e NO_3RR based on the first-principles calculations. Interestingly, the AE metal

active centers in the built AE metal single-atom catalyst (AE-SAC) can strongly adsorb and effectively activate NO_3^- ions, similar to the cases of the TM active centers. Intriguingly, by changing the active center identities and their coordination environment, the binding strength of NO_3^- can be tuned properly to realize high e NO_3RR activity. Especially, Ba and Sr SACs coordinated with one C and three N atoms exhibit ultra-high e NO_3RR activity with near-zero limiting potential (U_L) of -0.05 V , together with desirable selectivity and good stability, comparable or even better than the TM-based SACs reported so far. Furthermore, the underlying mechanism for the effective NO_3^- activation and the excellent e NO_3RR activity on the AE metal active centers were explored.

2. Computational methods

All the spin-polarized density functional theory (DFT) calculations were performed based on the projector augmented wave (PAW)⁵⁵ method as implemented in the Vienna *ab initio* simulation package (VASP).⁵⁶ Perdew–Burke–Ernzerhof (PBE) functional within the generalized gradient approximation (GGA) was employed to treat the exchange-correlation effect.⁵⁷ The plane-wave cutoff energy was 450 eV . The van der Waals correction was performed using the DFT-D3 method.⁵⁸ The energy and force convergence criteria for the structural optimization were set as 10^{-5} eV and 0.02 eV \AA^{-1} , respectively. The AE-SAC was built based on the $5 \times 5 \times 1$ graphene supercell. The effect of relaxing lattice parameters on the adsorption stability was tested, and it was found that thanks to the large supercells, relaxing the lattice parameters has negligible influence on the adsorption energy (Fig. S1†). The Monkhorst–Pack scheme was used to sample the first Brillouin zone,⁵⁹ and the k -points grids were $3 \times 3 \times 1$ and $6 \times 6 \times 1$ for the structural optimization and densities of states (DOS) calculation, respectively. We also tested the DOS calculated with the hybrid functional of Heyd–Scuseria–Ernzerhof (HSE06),⁶⁰ and results indicate that the distributions of electronic states were very similar for PBE and HSE06 functionals (Fig. S2†). Given that all the AE-SACs studied in this work exhibited obviously metallic features without a band gap, thus the DOS calculated with the PBE functional was qualified. To avoid the interaction between the periodic units, a vacuum layer of $\sim 20 \text{ \AA}$ was added along the z direction. *Ab initio* molecular dynamics (AIMD) simulation was carried out to estimate the thermal stability with a time step of 2 fs .⁶¹

To explore the accessibility of the experimental synthesis, the formation energy (E_f) was calculated using the following formula:^{62,63}

$$E_f = E_{\text{total}} - E_G + \sum n_i \mu_i \quad (1)$$

in which, E_{total} and E_G are the total energies of AE-SAC and 5×5 graphene supercell, respectively. μ_i represents the chemical potential of the i species. n_i is the number of the removed and added i species, where the positive and negative values are referred to the removed and added species, respectively. The chemical potentials of the involved species, μ_C , μ_N , and μ_{AE} were calculated using a pristine graphene unit cell, N_2 free molecule,

and AE metal bulk, respectively. It should be mentioned that the E_f is closely related to the chemical potentials of the referred species, which is in turn dependent on the experimental conditions.

To estimate the binding strength between AE metal and the N-doped graphene substrate, the binding energy (E_b) is expressed as:

$$E_b = E_{\text{total}} - E_{\text{substrate}} - E_{\text{AE}} \quad (2)$$

where E_{total} and $E_{\text{substrate}}$ represent the total energies of N-doped graphene substrate with and without anchored AE metals, E_{AE} is the total energy of isolated AE metal atoms. The more negative E_b implies higher stability of AE-SACs.

In addition, to further verify the thermodynamical stability of the AE-SAC systems, the energy difference (ΔE_b) between E_b and E_{coh} was calculated.⁶⁴ In which, E_{coh} is the cohesive energy of AE metal bulk and can be calculated using the formula of $E_{\text{coh}} = (E_{\text{bulk}} - nE_{\text{AE}})/n$, where E_{bulk} is the total energy of the AE metal crystal and n is the number of metal atoms in the crystal. A negative ΔE_b indicates that the AE metal single atom tends to remain isolated on the substrate rather than agglomerate, and a more negative ΔE_b means higher thermodynamical stability.

The computational hydrogen electrode (CHE) mode⁶⁵ was adopted to calculate the Gibbs free energy change (ΔG) for each elementary step as follows

$$\Delta G = \Delta E + \Delta E_{\text{ZPE}} - T\Delta S \quad (3)$$

In the equation, ΔE is the electronic energy contribution directly obtained from DFT calculations. ΔE_{ZPE} and $T\Delta S$ are the contributions of zero-point energy and entropy (at 298.15 K), respectively, which could be acquired by computing the vibrational frequency for intermediates and from the NIST database⁶⁶ for free molecules (tabulated in Tables S1 and S2†). The limiting potential (U_L) was formalized with $U_L = -\Delta G_{\text{max}}/e$, where ΔG_{max} is the maximum free energy change among all elementary steps along the lowest-energy pathway, *i.e.*, the potential-determining step (PDS).⁶⁷ In light of the difficulty of directly calculating the energy of charged NO_3^- , the adsorption free energy of NO_3^- ($\Delta G^*(\text{NO}_3^-)$) was calculated with the assistance of the gaseous HNO_3 (ref. 36 and 68) as follows

$$\Delta G^*(\text{NO}_3^-) = G^*(\text{NO}_3^-) - G^*(\text{HNO}_3) - 0.5 \times G(\text{H}_2) + \Delta G_{\text{correct}} \quad (4)$$

Here, G^* and $G^*(\text{NO}_3^-)$ are the Gibbs free energies of the bare catalyst and that with the adsorbed NO_3^- , respectively. $G(\text{HNO}_3)$ and $G(\text{H}_2)$ represent the Gibbs free energies of the HNO_3 and H_2 molecules, respectively. The solvation correction was carried out with an implicit solvation model as implemented in VAS-Psol.⁶⁹ It is worth mentioning that we have studied the eNO_3RR process on an experimentally reported DV-FeN₄ system.³⁸ As seen in Fig. S3,† good consistency between the theoretical limiting potential (−0.38 V) and experimental on-set potential (−0.4 V) indicates the reliability of our computational settings.

3. Results and discussion

3.1. The properties of AE-SACs

With various merits, such as facile fabrication, excellent stability, and easily tunable electronic structure, graphene-based SACs have received considerable attention for various electrocatalytic reactions.⁷⁰ Moreover, regulating the coordination environment of the active center can greatly affect its catalytic activity and selectivity.^{53,54} Herein, we constructed a series of AE-SACs, where the AE metal (Mg, Ca, Sr, Ba) single-atoms are embedded into graphene with single vacancy or double vacancy decorated by certain numbers of N atoms, as illustrated in Fig. 1. Considering that Be is extremely toxic⁷¹ and Ra is a typical radioactive element,⁷² they are not involved in this work. By adjusting the number of coordinated N atoms, seven DV-MN_xC_{4-x} and four SV-MN_xC_{3-x} configurations were established for each AE metal single atom, producing 44 SAC candidates. The key parameters of these systems are listed in Table S3,† including bond length, charge transfer, spin magnetic moment, formation energy, and binding energy.

The experimentally synthetic feasibility of the proposed AE-SACs can be estimated theoretically from the formation energy.^{62,63} Since MgN₂C₂-III was synthesized experimentally,¹⁴ was selected as a benchmark. It can be seen from Fig. 2a that the lower the number of coordinated N atoms, the higher the formation energy. More importantly, except DV-MNC₃, DV-MC₄, SV-MNC₂, and SV-MC₃, all the AE-SACs have lower or comparable formation energies compared with MgN₂C₂-III, strongly suggesting that they are able to be synthesized experimentally too. Furthermore, as shown in Fig. 2b, the significantly negative binding energies for all the AE-SACs (except DV-MgC₄) indicate that there are strong chemical bonds between AE metals and their neighboring C or N atoms. Clearly, for all AE-SACs (except DV-MgC₄ and SV-MgNC₂), the energy differences (ΔE_b) between E_b and E_{coh} are less than zero (Fig. 2c), suggesting that when the AE-SACs are synthesized, the AE metals prefer to be dispersed on the supports instead of agglomerating into nanoparticles, which further demonstrates their high thermodynamical stability. Finally, the Bader charge analysis⁷³ shows that the AE metals lose most of their valence electrons (~1.5e) to graphene and form AE cations, similar to the AE elements in other compounds. Therefore, it is expected that the AE-SACs could bind NO_3^- effectively. In addition, the total DOS of all the AE-SAC systems (Fig. S4–S7†) indicate their metallic characteristics, which facilitate the charge transfer during eNO_3RR .⁷⁴

3.2. Adsorption of NO_3^- on AE-SACs

As an initial and pivotal step for the eNO_3RR process, NO_3^- should be adsorbed on the active center effectively. As illustrated in Fig. S8a,† all the possible NO_3^- adsorption configurations have been taken into account, including those with one O atom or two O atoms binding, and the parallel pattern. In addition, we have also considered several possible adsorption positions around the AE metal active centers for $^*\text{NO}_3$ and the other key reaction intermediates (Fig. S8b†). The most stable adsorption configurations for $^*\text{NO}_3$ are shown in Fig. S9,†



Fig. 1 Schematic illustrations of the AE-SAC systems with single Mg/Ca/Sr/Ba atom anchoring on the graphene support with different coordination environments.

meanwhile, some important parameters (bond length, charge transfer, and $\Delta G(^*\text{NO}_3)$) are displayed in Table S4.† We can see that for all the cases the configuration with two O atoms binding with the AE metal atom is the most stable. Intriguingly, the values of $\Delta G(^*\text{NO}_3)$ are all less than -1.0 eV (ranging from -1.18 to -3.26 eV), indicating that the active site consisting of AE metal can strongly adsorb NO_3^- , similar to the TM active site.^{33,45} However, contrary to TM active sites, for all the systems, a considerable amount of charge transfers ($\sim 1.6e$) from the catalysts to NO_3^- can be observed, suggesting that the binding of NO_3^- mainly relied on the ionic bond interaction, for which the detailed analysis will be presented below.

It is known that hydrogen evolution reaction (HER) is the main competing reaction against eNO_3RR mainly because protons can also bind with the active sites.³³ To effectively inhibit this disadvantage, active sites should be preferentially occupied by NO_3^- instead of H atoms, which requires strong adsorption of NO_3^- compared with H.^{45,51} The adsorption configurations for $^*\text{H}$ are displayed in Fig. S10,† meanwhile, some important parameters (bond length, charge transfer, and $\Delta G(^*\text{H})$) are compiled in Table S5.† As shown in Fig. 3a, for all the systems, $\Delta G(^*\text{NO}_3)$ is negative, while $\Delta G(^*\text{H})$ is positive (except SV-MgN₃), indicating that the adsorption of NO_3^- is much stronger than that of H atoms. Therefore, eNO_3RR will



Fig. 2 The calculated formation energy, E_f (a), binding energy, E_b (b), and the energy difference between E_b and E_{coh} , ΔE_b (c) for the AE-SAC systems. DV-MgN₂C₂-III is adopted as a reference for the formation energy.



Fig. 3 Adsorption free energy (ΔG) (a) and charge transfer (Q) (b) for NO_3^- and H adsorption on the considered AE-SAC systems. $Q_{\text{M-NO}_3}$ and $Q_{\text{M-H}}$ denote the charge transfer of AE metals, and Q_{NO_3} and Q_{H} are the charge transfer of *NO_3 and *H , respectively. The positive and negative values represent the electron loss and electron gain, respectively.

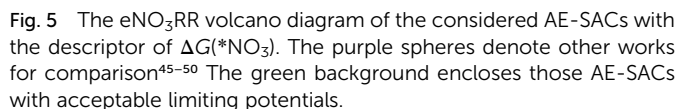
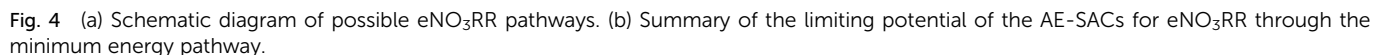
dominate and the HER can be effectively inhibited on these SACs. By analyzing the charge transfer (Fig. 3b), it is found that, for all the cases, NO_3^- gains more electrons from SACs than H atoms, and the NO_3^- bonded AE metal atoms carry more positive charges than the H -bonded ones, which could be responsible for the much stronger binding of NO_3^- .

3.3. Mechanism of eNO_3RR on AE-SACs

From the previously reported results, the binding strength of NO_3^- can serve as the activity descriptor for eNO_3RR , and for various kinds of SACs, the active sites with $\Delta G(\text{*NO}_3)$ of around -2 eV show high eNO_3RR activity.^{45–48} Above results show that by changing the AE metal active center and its coordination environment, $\Delta G(\text{*NO}_3)$ values can be adjusted from -1.18 to -3.26 eV. Therefore, it is expected that the AE-SACs can achieve high catalytic activity for eNO_3RR . Despite the complex eNO_3RR process with multiple products, according to the Pourbaix diagram of nitrogen species, $\text{NH}_3/\text{NH}_4^+$ has been identified as the most stable product in thermodynamics under negative electrode potential.^{45,75} Therefore, it is essential to make a thorough investigation of the reaction mechanism of the selective electroreduction of NO_3^- to NH_3 . Fig. 4a displays the exhaustive reaction pathways of eNO_3RR , where all the possible configurations of *HNO_3 , *NO_2 , and *HNO_2 have been considered. Given the multiple configurations and

hydrogenation positions of intermediates during the eNO_3RR process, to economically and effectively obtain the optimal pathway, only the most stable structure in each elementary step is chosen to further study the subsequent reaction. Generally, U_L has been used to evaluate the catalytic activity of an electrocatalytic reaction,⁶⁵ and the calculated U_L for these AE-SACs are shown in Fig. 4b and tabulated in Table S6.† Surprisingly, in contrast with the traditional view that the AE metal active centers are catalytically inactive, most of the AE-SACs exhibit a high eNO_3RR activity with U_L lower than -0.6 V. Especially, DV-SrN₃C and DV-BaN₃C possess the highest eNO_3RR activity with an ultralow U_L of -0.05 V. This value is much lower than those of the previous predicted TM-based SACs. For example, U_L of Ti/g-CN,⁴⁵ Hf/g-C₃N₄,⁴⁶ Ru/g-C₃N₄,⁴⁷ V/g-C₃N₄,⁴⁸ Os/GDY,⁴⁹ V/h-BP,⁵¹ and Fe/NG⁵² are -0.39 , -0.11 , -0.34 , -0.25 , -0.37 , -0.22 , and -0.38 V, respectively. Therefore, the catalysts with active sites consisting of AE metal could be even superior to those consisting of TM.

The calculated U_L as a function of $\Delta G(\text{*NO}_3)$ is presented in Fig. 5, interestingly, which also exhibits a prototypical volcano-shaped correlation, similar to the case of SACs with TM as the active center.^{45,47–49,52} One can see that, on the left branch of the volcano diagram, too strong adsorption of NO_3^- often leads to the last hydrogenation step ($\text{*OH} \rightarrow \text{*} + \text{H}_2\text{O}$) as PDS, while the relatively weak adsorption of NO_3^- results in the early



addition to DV-SrN₃C and DV-BaN₃C, there are also a large number of other AE-SAC systems (highlighted by the green background in Fig. 5) possessing acceptable U_L , which are comparable to the reported TM catalysts, marked by the purple circle in Fig. 5.^{45–50} Furthermore, it is noted that $\Delta G(^*NO_3)$ of the above AE-SACs stand in the range from -1.3 to -2.5 eV, similar to the systems with TM active centers.^{45–50}

To get more insight into the reaction mechanism, the eNO_3RR pathways on DV-Ba N_3C and DV-Sr N_3C are plotted in Fig. 6, and those for other systems are depicted in Fig. S11–S16.[†] Interestingly, on DV-Ba N_3C , the first hydrogenation step of *NO_3 occurs at the O site bonded to the Ba atom, generating the co-adsorbed *OH and *NO_2 with a free energy downhill of 0.40 eV (Fig. 6a), which is completely different from previous works that the proton–electron ($\text{H}^+ + \text{e}^-$) pair firstly attacks the terminal O of *NO_3 .^{45,51} The second hydrogenation step results in the release of the first H_2O molecule with the free energy downhill of 0.87 eV, leaving the NO_2 asymmetric adsorption on DV-Ba N_3C *via* one Ba–O bond and one Ba–N bond. Similar to the first hydrogenation step, the third $\text{H}^+ + \text{e}^-$ pair also prefers to attack the proximal O atom (bonded to Ba) of *NO_2 , breaking another N–O bond to form $\text{*OH} + \text{*NO}$ with the free energy uphill of only 0.02 eV. Then, the second water molecule is formed exothermically. The *NO trends to adopt the end-on pattern with the N atom bonding to the Ba atom, similar to the cases of TM active centers.^{45,51} Then, the fifth $\text{H}^+ + \text{e}^-$ pair



Fig. 6 Free energy diagrams together with corresponding intermediate configurations for eNO₃RR on DV-BaN₃C (a) and DV-SrN₃C (b) under the potentials of 0, -0.05, and -0.2 V.

prefers to be added on the N atom of *NO, turning the end-on adsorption pattern to a side-on adsorption pattern, which is also identified as the PDS with a free energy uphill of 0.05 eV. The subsequent electroreduction processes are all exothermic. In detail, the hydrogenation of *HNO follows the pathway, *HNO → *H₂NO → *O + NH₃ (g) → OH* → * + H₂O (l), to recover the active center.

Overall, the eNO₃RR pathway on DV-SrN₃C (Fig. 6b) is almost the same as that on DV-BaN₃C, and the only difference is that the seventh hydrogenation step occurs on the O atom to form *H₂NOH, and NH₃ is released after the eighth hydrogenation step (*H₂NOH → *OH + NH₃ (g)). It is noted that all the reaction steps are exothermic on DV-SrN₃C, except the third (*NO₂ →

*OH + *NO) and fifth (*NO → *HNO) hydrogenation steps with the free energy uphill of 0.05 and 0.01 eV, respectively.

Moreover, we also calculated the adsorption-free energy of *H₂O (ΔG_{*H₂O}), and the reaction-free energy of the hydrogenation of *OH to *H₂O (ΔG_{*OH → *H₂O}) for the studied AE-SAC systems. As seen in Table S7,† the negative ΔG_{*OH → *H₂O} for most of the AE-SAC systems indicate that the hydrogenation of *OH to form *H₂O is spontaneous and quite easy, thereby, avoiding the *OH poisoning. It is worth mentioning that the SV-MgN₃, SV-CaN₃, and SV-SrN₃ systems with large ΔG_{*OH → *H₂O} exhibit poor catalytic activity, which requires a high potential to remove *OH. Moreover, the ΔG_{*H₂O} values for all AE-SAC systems are larger than -0.6 eV, indicating the weak adsorption of H₂O in the AE-SAC systems. Combining the

aforementioned stronger adsorption of $^*\text{NO}_3$ than $^*\text{H}$, it can be concluded that the $^*\text{H}$, $^*\text{OH}$, and $^*\text{H}_2\text{O}$ will not poison the proposed catalysts (except $\text{SV-MgN}_3\text{C}$, $\text{SV-CaN}_3\text{C}$, and $\text{SV-SrN}_3\text{C}$).

For the reaction selectivity, besides the aforementioned HER, other byproducts, mainly NO_2 , NO , N_2O , and N_2 , during eNO_3RR may be produced. It can be seen from Fig. 6 that direct desorption of $^*\text{NO}_2$ from $\text{DV-BaN}_3\text{C}$ and $\text{DV-SrN}_3\text{C}$ is extremely difficult because large energy barriers as high as ~ 2 eV are needed to overcome. Although the desorption energy barriers of $^*\text{NO}$ are not particularly high as NO_2 (0.39 and 0.55 eV), they are much higher than those for further hydrogenation (0.05 and 0.01 eV). Especially, when a tiny potential was applied, the further hydrogenation of $^*\text{NO}$ would be much more favorable thermodynamically. For instance, with an applied potential of -0.2 V, the free energy difference between the NO desorption and hydrogenation will exceed 1.3 eV. Therefore, $^*\text{NO}$ will further undergo electrochemical hydrogenation on $\text{DV-BaN}_3\text{C}$ and $\text{DV-SrN}_3\text{C}$. On the other side, the NO dimer (N_2O_2) with cis O=N-N=O structure is the vital precursor to form N_2O and N_2 , which could be formed by the coupling of two NO .^{49,76,77} Obviously, the isolated single-atom active site cannot accommodate two NO_3^- simultaneously, and thus Langmuir-Hinshelwood mechanism for the formation of NO dimer can be excluded.⁷⁸ For the Eley-Rideal mechanism, the $^*\text{NO}$ needs to combine with a solvated NO molecule to form a NO dimer.⁷⁹ However, due to that $^*\text{NO}$ will be further hydrogenated rather than desorbed, the Eley-Rideal mechanism for NO dimer formation is also infeasible. Hence, the formation of NO_2 , NO , N_2O , and N_2 will be effectively inhibited. Moreover, the desorption of the target product NH_3 is exothermic and spontaneous, further confirming high eNO_3RR selectivity toward NH_3 on $\text{DV-BaN}_3\text{C}$ and $\text{DV-SrN}_3\text{C}$.

The electrode potential could significantly affect the selectivity of eNO_3RR against HER.³⁶ To be specific, the more negative electrode potential can bring more positive $\Delta G(^*\text{NO}_3)$ but more negative $\Delta G(^*\text{H})$, so the adsorption of NO_3^- will become less favorable, whereas, the adsorption of the H atom may be dominant, exacerbating the selectivity problem. As shown in Fig. S17,[†] the adsorption of NO_3^- is still stronger than that of H on $\text{DV-BaN}_3\text{C}$ and $\text{DV-SrN}_3\text{C}$ even after applying a potential as large as -1.0 V. Therefore, the robust adsorption of NO_3^- could completely suppress the HER under the limiting potential, again affirming the high eNO_3RR selectivities of $\text{DV-BaN}_3\text{C}$ and $\text{DV-SrN}_3\text{C}$.

Finally, the effect of the solvation on eNO_3RR was investigated for $\text{DV-BaN}_3\text{C}$ and $\text{DV-SrN}_3\text{C}$. One can see from the free energy diagrams in Fig. S18[†] that the overall reaction pathway and PDS were unchanged when considering the solvation correction. In addition, U_L values are slightly decreased by 0.05 and 0.06 V for $\text{DV-BaN}_3\text{C}$ and $\text{DV-SrN}_3\text{C}$ with solvation correction, respectively, similar to other works.^{39,48,49}

3.4. Activity origin of eNO_3RR on AE-SACs

As the binding strength of NO_3^- can well predict the activity trend of eNO_3RR , the investigation of its activation mechanism and binding strength change, based on the electronic structure

analysis, could give us insight into the activity origin. For comparison, $\text{DV-BaN}_3\text{C}$ and $\text{SV-MgN}_3\text{C}$ were considered, and they exhibited the highest ($U_L = -0.05$ V) and lowest ($U_L = -1.48$ V) eNO_3RR activity, respectively. Firstly, the charge density difference (CDD) is displayed in Fig. 7a and b show that considerable electrons are transferred from the embedded AE metals to the graphene support, and the AE metal atoms should be significantly positively charged, which is in agreement with the Bader charge analysis (1.42e for Ba and 1.20e for Mg). Consequently, the AE metals are stabilized by mainly ionic bond interaction, as verified by electron localization function (ELF) analysis. The positively-charged AE metals are responsible for the stable adsorption of the oxygenated species. For the adsorption of NO_3^- on $\text{DV-BaN}_3\text{C}$ and $\text{SV-MgN}_3\text{C}$, Bader charge analysis gives that $^*\text{NO}_3$ gains 0.86 and 0.87e from the support, respectively. NO_3^- adsorbed Ba and Mg were positively charged by 1.62 and 1.64, respectively. Therefore, the adsorption of NO_3^- is mainly through the ionic bond interaction. However, from Fig. 7c and d, ELF results show that there is a certain charge overlap between $^*\text{NO}_3$ and its bonded AE metal atoms, and especially, more electrons are located between $^*\text{NO}_3$ and Mg than $^*\text{NO}_3$ and Ba, indicating stronger covalent interaction between $^*\text{NO}_3$ and Mg. It is worth noting that the charge enclosed on the Ba atom of the $\text{DV-BaN}_3\text{C}$ system is an indicator of its lone-pair electrons. Importantly, CDD for NO_3^- adsorbed systems indicates that charge accumulation and depletion occur simultaneously on $^*\text{NO}_3$. Especially, the electrons obtained by $^*\text{NO}_3$ mainly occupy its antibonding orbitals (positive section around the periphery of O atoms of $^*\text{NO}_3$, as shown in Fig. 7c and d), while $^*\text{NO}_3$ also loses some charges from its bonding orbitals (negative section on the N-O bonds of $^*\text{NO}_3$, as shown in Fig. 7c and d). Therefore, NO_3^- can be effectively activated by the AE metal active center, through the “donation-back donation” mechanism, similar to the cases of TM active center,^{51,52} the reason for which will be discussed later.

The above picture of NO_3^- adsorption can be supported by the DOS analysis. From Fig. 7e and f, we can see that a large number of electronic states of the O atoms in $^*\text{NO}_3$, which are bonded with the AE metal atom, are located below the Fermi level, while the electronic states of the Ba and Mg atoms are very few. This result is in line with the ionic bond nature discussed above. Furthermore, crystal orbital Hamilton population (COHP)⁸⁰ analyses are shown in Fig. 7e and f indicate that there are more bonding states (positive value) between $^*\text{NO}_3$ and Mg than those between $^*\text{NO}_3$ and Ba. In addition, there are also some antibonding states occupied between $^*\text{NO}_3$ and Ba (negative value). Integrated COHP (ICOHP) can quantitatively characterize the covalent interaction strength, that is, a more negative ICOHP signifies a stronger chemical bond interaction. The ICOHP (-5.94 eV) for the Mg-O bond is much more negative than that for the Ba-O bond (-2.82 eV). This verifies the stronger covalent interaction between $^*\text{NO}_3$ and Mg than $^*\text{NO}_3$ and Ba. Indeed, $\Delta G(^*\text{NO}_3)$ was as high as -3.26 eV, for $\text{SV-MgN}_3\text{C}$, which resulted in a large energy barrier (1.48 eV) in the last step of $^*\text{OH} \rightarrow ^* + \text{H}_2\text{O}$ (Fig. S11c[†]). In contrast, the moderate chemical activity of the Ba active center in $\text{DV-BaN}_3\text{C}$ endows it with ultrahigh eNO_3RR activity.



Fig. 7 The charge density difference (CDD) and electron localization function (ELF) for the bare DV-BaN₃C (a), bare SV-MgN₃ (b), NO₃ adsorbed DV-BaN₃C (c) and NO₃ adsorbed SV-MgN₃ (d). Projected densities of states (PDOS) and COHP for the NO₃ adsorbed DV-BaN₃C (e) and NO₃ adsorbed SV-MgN₃ (f). For CDD, the yellow and cyan regions denote electron accumulation and depletion, respectively, and the isosurface value was set to 0.002 e/bohr⁻³. In PDOS and COHP, the Fermi level (E_F) is labeled by a vertical dash line and set to 0 eV. COHP was calculated for the interaction between NO₃⁻ and Ba (Mg).

In order to further understand the excellent catalytic activity of the AE active center for eNO₃RR, the charge variations along with the reaction pathway for DV-BaN₃C and DV-SrN₃C were analyzed by subdividing the systems into three moieties, *i.e.*, the N-doped graphene (moiety1), AE metal atom (moiety2), and adsorbate (moiety3), as illustrated in Fig. S19.† The detailed charge variations of the three moieties are presented in Fig. 8a and b, where steps 0 and 1 represent the charge distribution of the bare support and the NO₃⁻ adsorbed support, and steps 2–9 are the subsequent hydrogenation steps. Concretely, during the eNO₃RR reaction processes, the net charge of the Ba and Sr atoms remains almost unchanged (~1.50e), and the charge change trends are similar for DV-BaN₃C and DV-SrN₃C. Meanwhile, the charges of the support (moiety1) dynamically change, which exchange charges with the intermediates indirectly with the AE ion as transmitters. Especially, the electron reservoir nature of the support enables the activation of NO₃⁻ following the charge “donation-back donation” mechanism, mimicking the behavior of TM active centers.^{51,52}

As discussed above, the thermodynamic stability of DV-BaN₃C and DV-SrN₃C was confirmed. Next, the thermal stability

was further checked through AIMD simulation. As plotted in Fig. 8c and d, the temperature and energy curves oscillate near the equilibrium states, and the DV-BaN₃C and DV-SrN₃C almost retain their intact geometric structures after 10 ps AIMD simulations under 600 K, implying their high thermal stability. Kinetically, Fig. 8e and f show that the energy differences between the most stable configuration and the second stable one with the Ba and Sr near the hollow sites are as large as 3.50 and 3.97 eV, respectively. Such high energy barriers mean that the diffusion of Ba or Sr atoms is unlikely on the graphene support, confirming the kinetic stability. Finally, the electrochemical stability was also evaluated by calculating the dissolution potential (U_{diss}).⁶⁷ The obtained U_{diss} are -0.90, -1.26, and -1.27 V for DV-MgN₂C₂-III, DV-SrN₃C, and DV-BaN₃C systems, respectively. Considering that DV-MgN₂C₂-III SAC was experimentally synthesized and used in the oxygen reduction reaction,¹⁴ DV-SrN₃C and DV-BaN₃C SACs are also stable enough under the electrochemical conditions due to their comparable U_{diss} values compared with the experimentally synthesized MgN₂C₂-III system.

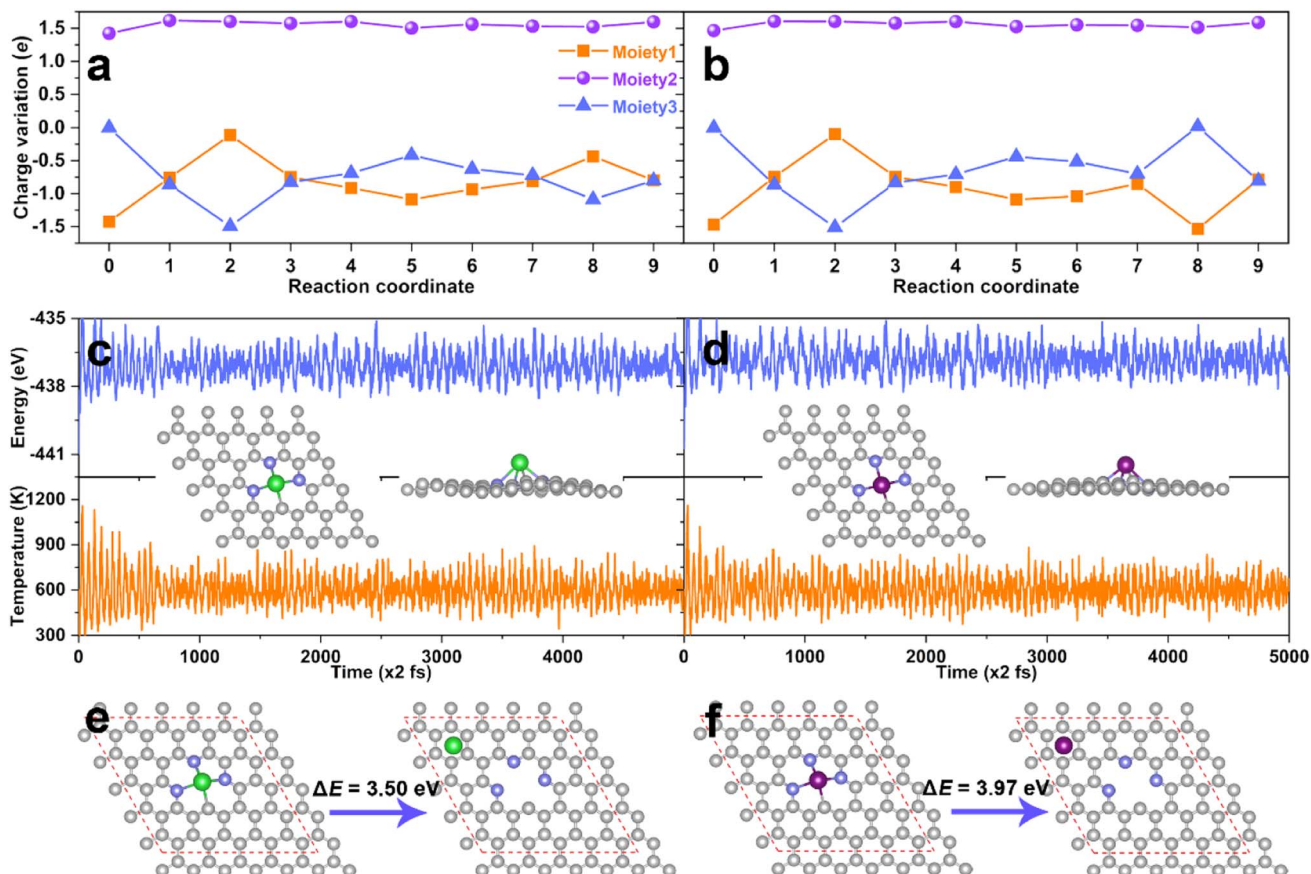


Fig. 8 The charge variation during the eNO₃RR process on DV-BaN₃C (a) and DV-SrN₃C (b). Energy and temperature evolution during the AIMD simulation for DV-BaN₃C (c) and DV-SrN₃C (d). Insets are the top and side views of the snapshots after 10 ps. The most stable configuration and second stable one with the Ba (e) and Sr (f) near the hollow sites, where ΔE is their energy difference.

4. Conclusions

In summary, based on the first-principles calculations, the feasibility of AE metals as active centers for eNO₃RR to produce NH₃ was systematically investigated by taking a series of AE-SACs as representatives, which were constructed by embedding AE metal (Mg, Ca, Sr, Ba) single atom into the N-doped graphene. Surprisingly, similar to the TM active sites, it was found that the AE metal active centers could also strongly adsorb and effectively activate NO₃[−], to achieve excellent eNO₃RR activity. By thoroughly investigating the possible reaction pathways, a volcano diagram was established with $\Delta G^*(\text{NO}_3)$ as the descriptor. The DV-BaN₃C and DV-SrN₃C systems were exactly located around the peak of the volcano diagram, exhibiting the highest activity for eNO₃RR to produce NH₃ with near-zero U_L of -0.05 V, comparable and even better than the TM-based SACs. With good stability, both systems also exhibited excellent selectivity against the generation of the byproducts, including H₂, NO₂, NO, N₂O, and N₂. Moreover, the electronic structure analysis indicates that although AE metal elements are highly ionic during the reaction, the support can indirectly exchange charge *via* the AE cations with NO₃[−] and intermediates effectively, which enables the effective activation of NO₃[−], *via* the charge “donation-back donation” mechanism,

and further completes the catalytic cycle. On the one hand, these findings propose a novel kind of electrocatalyst for eNO₃RR, which may be also suitable for other reactions. Moreover, this work lays a theoretical foundation for the development of heterogeneous catalysts with AE metal as active centers, and emphasizes the great potential of AE metals, beyond transition metals, as active centers in heterogeneous catalysis.

Conflicts of interest

The authors declare no conflicts of interest.

Acknowledgements

This work is supported by the National Natural Science Foundation of China (Grant No. 12074099) and the Program for Science & Technology Innovation Talents in Universities of Henan Province (Grant No. 20HASTIT028).

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